

March 2012 SuperFET[®] II

FCPF400N60 600V N-Channel MOSFET

Features

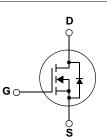
- 650V @T_J = 150°C
- Max. R_{DS(on)} = 400mΩ
- Ultra low gate charge (typ. $Q_g = 28nC$)
- Low effective output capacitance (typ. C_{oss} .eff = 90pF)
- 100% avalanche tested

Description

SuperFET[®]II is, Fairchild's proprietary, new generation of high voltage MOSFET family that is utilizing an advanced charge balance mechanism for outstanding low on-resistance and lower gate charge performance.

This advanced technology has been tailored to minimize conduction loss, provide superior switching performance, and withstand extreme dv/dt rate and higher avalanche energy. Consequently, SuperFET[®]II is very suitable for various AC/DC power conversion in switching mode operation for system miniaturization and higher efficiency.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter			FCPF400N60	Units	
V _{DSS}	Drain to Source Voltage			600	V	
V _{GSS}		-DC		±20	V	
	Gate to Source Voltage	-AC	(f>1HZ)	±30	V	
ID	Drain Current	-Continuous ($T_C = 25^{\circ}C$)		10*	٨	
		-Continuous ($T_C = 100^{\circ}C$)		6.3*	Α	
I _{DM}	Drain Current	- Pulsed (Note 1)		30*	А	
E _{AS}	Single Pulsed Avalanche Energy (Note		(Note 2)	211.6	mJ	
I _{AR}	Avalanche Current		(Note 1)	2.3	А	
E _{AR}	Repetitive Avalanche Energy		(Note 1)	1.06	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)			20	V/ns	
	MOSFET dv/dt			100		
P _D	Bower Discipation	$(T_{C} = 25^{\circ}C)$		31	W	
	Power Dissipation	- Derate above 25°C		0.25	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
Τ _L	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C	

*Drain current limited by maximum junction temperature

Thermal Characteristics

Symbol	Parameter	FCPF400N60	Units
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	4	
$R_{\theta CS}$	Thermal Resistance, Case to Heat Sink (Typical)	0.5	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	62.5	

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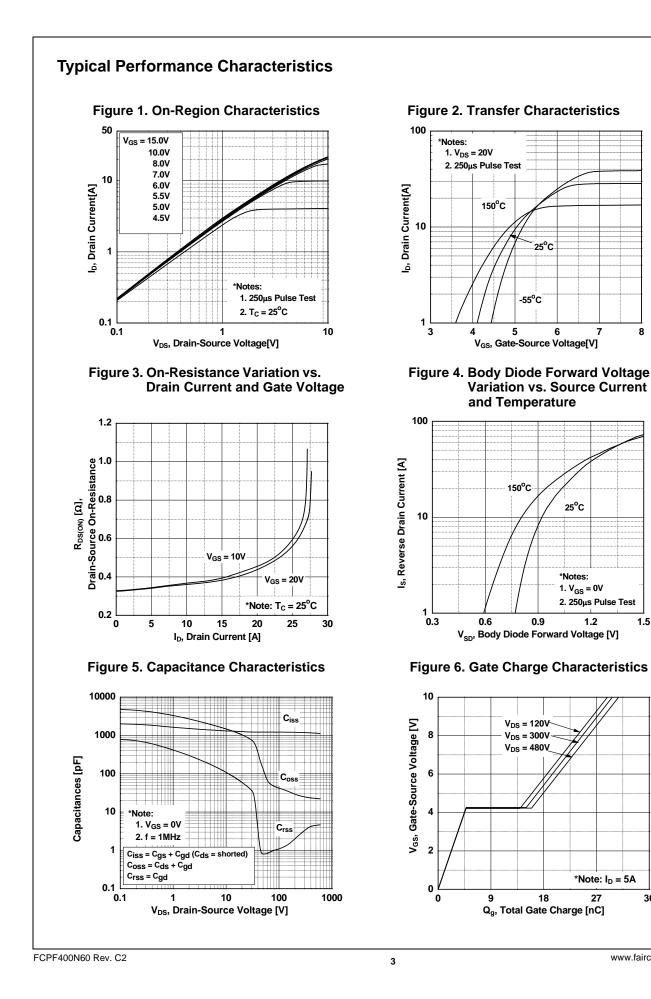
Device Marking FCPF400N60		Device FCPF400N60	Packag TO-220		Size 1	ape Width -		Quantity 50	
Electrica	al Chara	acteristics T _c =	25°C unless o	otherwise noted					
Symbol		Parameter		Test Con	ditions	Min.	Тур.	Max.	Unit
Off Charao	cteristics	S		L					
				V _{GS} = 0V, I _D = 10m	nA, T₁ = 25°C	600	-	-	V
BV _{DSS}	Drain to Source Breakdown Voltage		oltage	$V_{GS} = 0V, I_D = 10mA, T_J = 150^{\circ}C$		650	-	-	V
∆BV _{DSS}	Breakdown Voltage Temperature		ure	$I_D = 10$ mA, Referenced to 25°C		_	0.6	_	V/ºC
ΔT_{J}	Coefficient Drain-Source Avalanche Breakdown Voltage			$I_{\rm D}$ = 10mA, Referen	iced to 25°C	-	0.6	-	V/°C
BV _{DS}			kdown	V _{GS} = 0V, I _D = 10A		-	700	-	V
			$V_{DS} = 480V, V_{GS} = 0V$		-	-	1		
DSS	Zero Gate Voltage Drain Current		ent	$V_{DS} = 480V, T_{C} = 2$		-	-	10	μA
I _{GSS}	Gate to	Body Leakage Curren	ıt	$V_{GS} = \pm 20V, V_{DS} =$		-	-	±100	nA
On Charad	teristic	8		•					-
V _{GS(th)}	Gate Threshold Voltage			$V_{GS} = V_{DS}, I_{D} = 250 \mu A$		2.5	-	3.5	V
R _{DS(on)}		Static Drain to Source On Resistance		$V_{GS} = V_{DS}, I_D = 230 \mu A$ $V_{GS} = 10V, I_D = 5A$			0.35	0.40	Ω
9FS		Forward Transconductance		$V_{DS} = 20V, I_D = 5A$		-	11	-	S
Dynamic (Characte	eristics		1		L	1	1	
C _{iss}		Input Capacitance Output Capacitance Reverse Transfer Capacitance		V _{DS} = 25V, V _{GS} = 0V f = 1MHz		-	1180	1580	pF
C _{oss}						-	860	1144	pF
C _{rss}						-	43	54	pF
C _{oss}		Dutput Capacitance		V _{DS} = 380V, V _{GS} = 0V, f = 1.0MHz		z -	22	-	pF
C _{oss} eff.	-	Effective Output Capacitance		$V_{\rm DS} = 0V$ to 480V, $V_{\rm GS} = 0V$			90	-	pF
Q _{g(tot)}		otal Gate Charge at 10V		$V_{DS} = 380V, I_D = 5A$		-	28	38	nC
Q _{gs}		Gate to Source Gate Charge Gate to Drain "Miller" Charge		$V_{GS} = 10V$ (Note 4)		-	5	-	nC
Q _{gd}						. 4)	10	-	nC
ESR	Equivalent Series Resistance			Drain Open			1		Ω
Switching	Charact	teristics							
t _{d(on)}		Delay Time				-	13	37	ns
t _r	Turn-On	Turn-On Rise Time		$V_{DD} = 380V, I_D = 5A$ $V_{GS} = 10V, R_G = 4.7\Omega$		-	7	24	ns
t _{d(off)}	Turn-Off Delay Time					-	43	95	ns
t _f		Fall Time		(Note 4)		e 4) -	6	21	ns
•	rce Dioc	le Characteristic	5		·				
I _S	-	m Continuous Drain to		Forward Current		-	_	10	Α
I _{SM}		m Pulsed Drain to Sou				-	-	30	Α
V _{SD}		Source Diode Forward		$V_{GS} = 0V, I_{SD} = 5A$		-	-	1.2	V
t _{rr}		Recovery Time	0	$V_{GS} = 0V, I_{SD} = 5A$		-	240	-	ns
		Recovery Charge		$dI_{\rm F}/dt = 100A/\mu s$	·	-	2.7	-	μC

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7

8

1.5



36

27

*Notes:

80

100

125

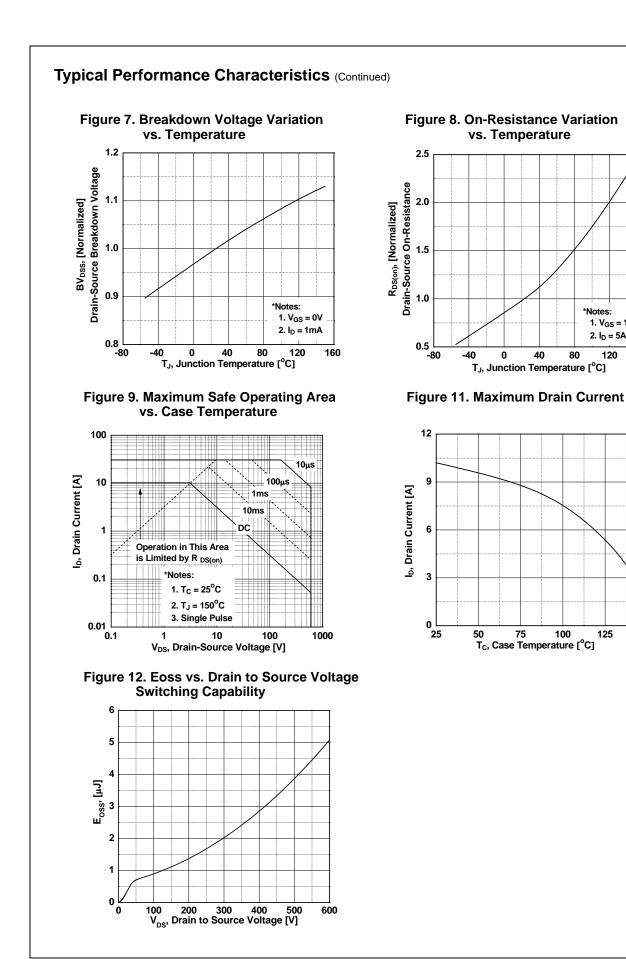
150

1. V_{GS} = 10V

2. I_D = 5A

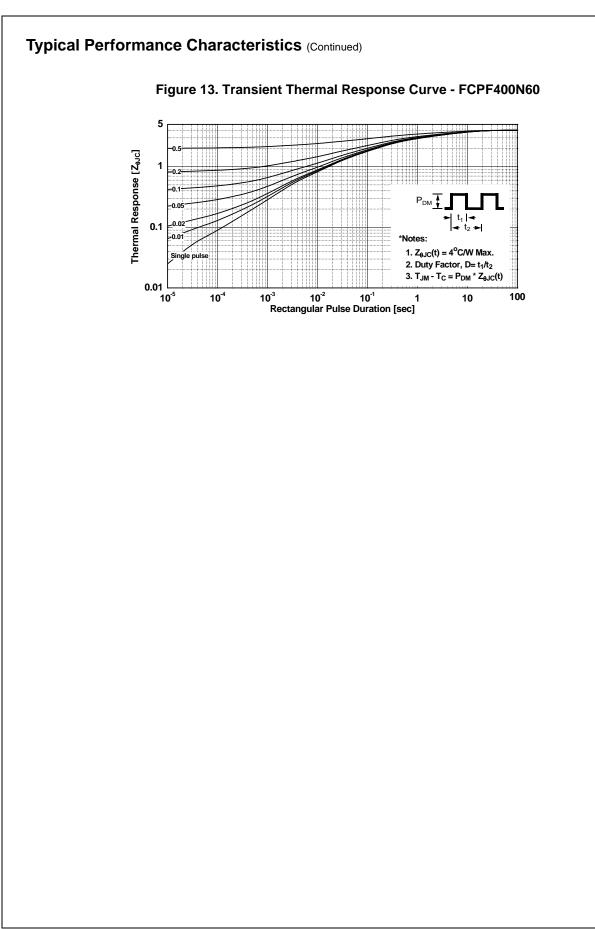
120

160



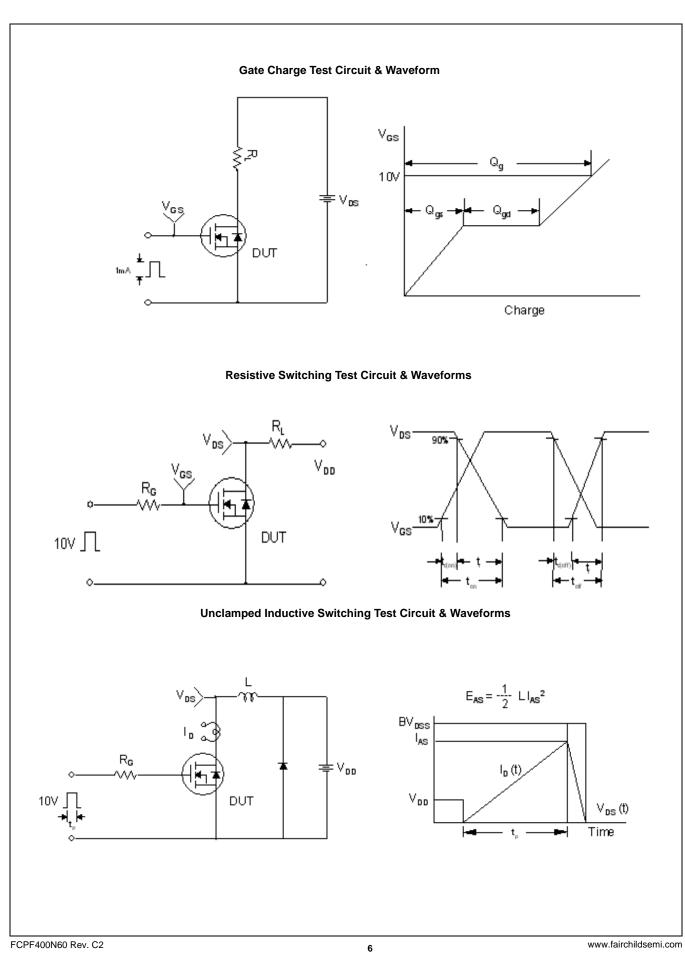
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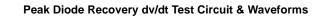


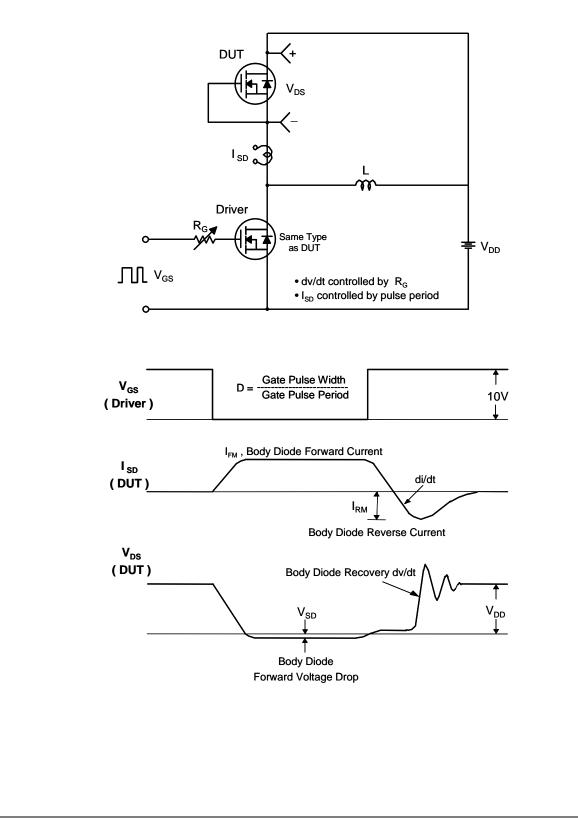
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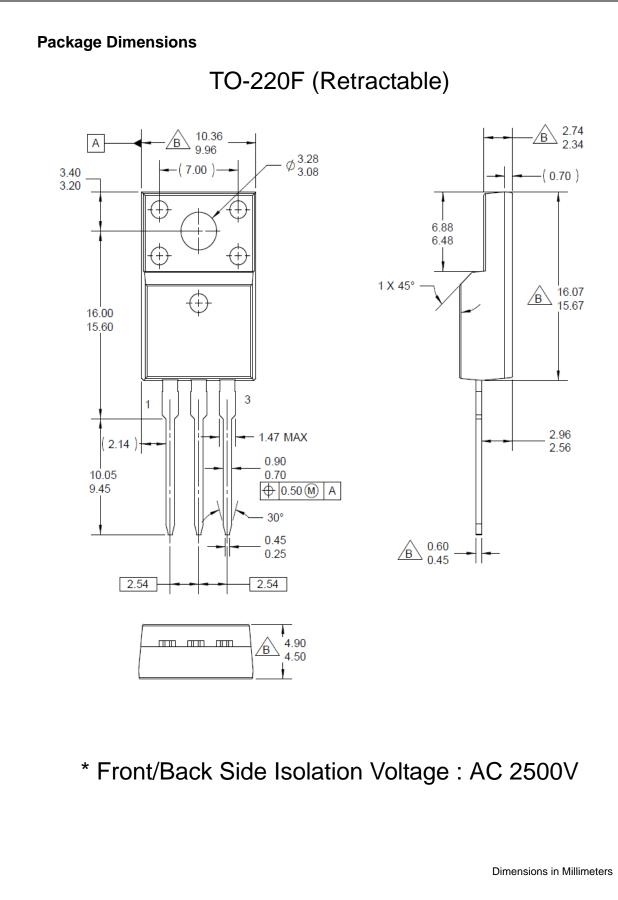


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